A Reduction Pathway in the Synthesis of PbSe Nanocrystal Quantum Dots

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Theoretical limit of solar cells using CM

✓ Slowered relaxation and cooling (~10X) of photogenerated hot e⁻ and h⁺.



Why PbSe QDs ?

➢ Band gap energy of 0.26 eV.

- Larger Bohr radius of PbSe compared to other semiconductor.
 - PbSe 23 nm vs. CdSe 1.5 nm
- > 8-fold degeneracy at the lowest electronic state.
- Highly efficient Carrier Multiplication (CM).

> Preparation methods

- Low production yield ~ 5%.
- Efficiency of CM depends on synthesis prep.
- Hard to control size (too fast growth rate).

Structure of NQDs solar cell



Band edge shift was calculated from effective approximation.

Reduction pathway using HDD



Effect of HDD on PbSe synthesis



Numerical simulation procedure



HDD effect on QDs growth dynamics





- HDD produces substantial amount of monomer in nucleation step.
- Fast nucleation when HDD was used.
- Sharp nucleation constructs the condition for high chemical yield and QY.

Conclusions

- High chemical yield and precise size control can be achieved by introducing HDD a s a reducing agent.
- ➢ High quantum yield can be achieved by using HDD.
- > Numerical simulation exactly describes nucleation and growth mechanism of QDs.

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